

## GENERAL PURPOSE SILICON RECTIFIER

# 1N5391 THRU 1N5399

**VOLTAGE RANGE**  
**CURRENT**

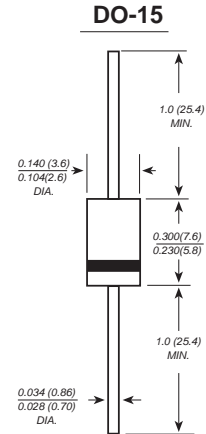
**50 to 1000 Volts**  
**1.5 Ampere**

### FEATURES

- The plastic package carries Underwriters Laboratory
- Flammability Classification 94V-0
- Construction utilizes void-free
- molded plastic technique
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length,  
5 lbs. (2.3kg) tension

### MECHANICAL DATA

- Case: JEDEC DO-15 molded plastic body
- Terminals : Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity : Color band denotes cathode end
- Mounting Position : Any
- Weight: 0.014 ounce, 0.40 grams



*Dimensions in inches and (millimeters)*

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified.
- Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	1N 5391	1N 5392	1N 5393	1N 5394	1N 5395	1N 5396	1N 5397	1N 5398	1N 5399	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	300	400	500	600	800	1000	VOLTS
Maximum RMS voltage	$V_{RMS}$	35	70	140	210	280	350	420	560	700	VOLTS
Maximum DC blocking voltage	$V_{DC}$	50	100	200	300	400	500	600	800	1000	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=75^\circ\text{C}$	$I_{(AV)}$	1.5									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	50.0									Amps
Maximum instantaneous forward voltage at 1.5A	$V_F$	1.4									Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	5.0 50.0									$\mu\text{A}$
Typical junction capacitance (NOTE 1)	$C_J$	20.0									pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0									$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +175									$^\circ\text{C}$

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted



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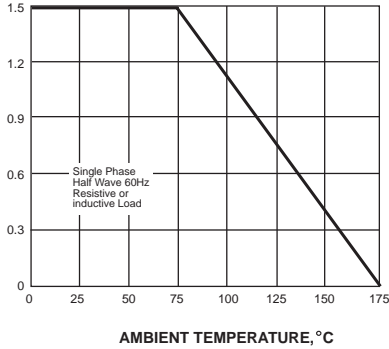
50 to 1000 Volts

CURRENT

1.5 Ampere

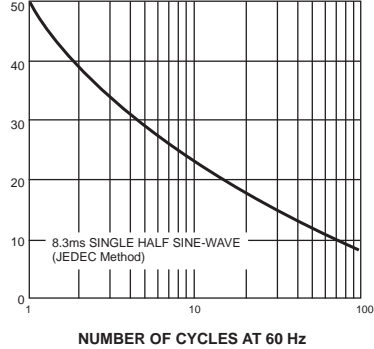
AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



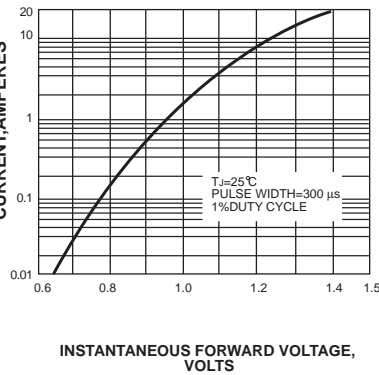
PEAK FORWARD SURGE CURRENT,  
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



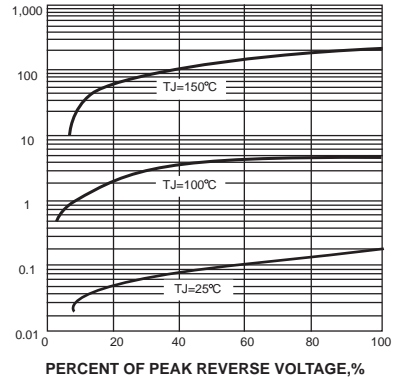
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



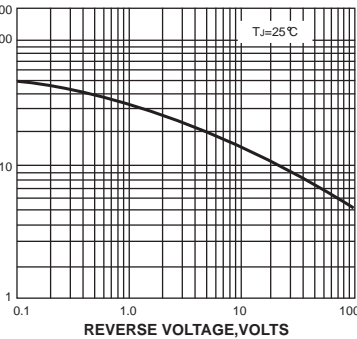
INSTANTANEOUS REVERSE CURRENT,  
MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,  
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

